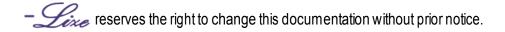
- Lize Shenzhen LIZE Electronic Technology Co., Ltd

SPECIFICATION

L93C46 Version 1.1



Features

► Low-voltage Operation

- 1.8 (VCC = 1.8V to 5.5V)

►Three-wire Serial Interface

▶2 MHz Clock Rate(5V) Compatibility

► Self-timed Write Cycle (5 ms max)

► High-reliability

- Endurance: 1 Million Write Cycles

- Data Retention: 100 Years

▶8-lead PDIP, 8-lead JEDEC SOIC and 8-lead TSSOP Packages

■ General Description

The L93C46 provides 1024 bits of serial electrically erasable programmable read only memory (EEPROM) organized as 64 words of 16 bits each, when the ORG pin is connected to VCC and 128 words of 8 bits each when it is tied to ground. The L93C46 is available in space-saving 8-lead PDIP, 8-lead TSSOP and 8-lead JEDEC SOIC packages. The L93C46 is enabled through the Chip Select pin (CS), and accessed via a 3-wire serial interface consisting of Data Input (DI), Data Output (DO), and Shift Clock (SK). Upon receiving a Read instruction at DI, the address is decoded and the data is clocked out serially on the data output pin DO. The WRITE cycle is completely self-timed and no separate erase cycle is required before write. The Write cycle is only enabled when it is in the Erase/Write Enable state. When CS is brought "high" following the initiation of a write cycle, the DO pin outputs the Ready/Busy status.

■ Pin Configuration

8-lead PDIP	8-lead SOIC	8-lead TSSOP
CS	CS	CS

■ Pin Descriptions

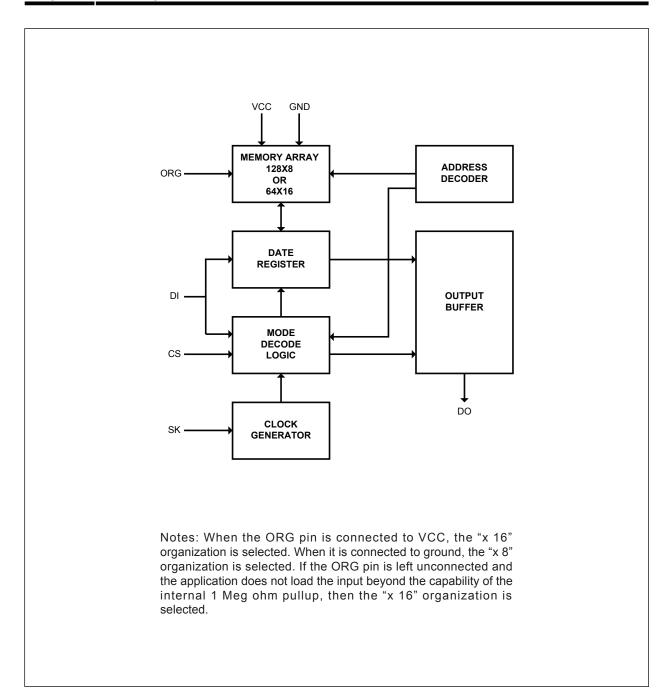
► Table 1: Pin Configuration

Pin Name	Function
CS	Chip Select
SK	Serial Data Clock
DI	Serial Data Input
DO	Serial Data Output
GND	Ground
Vcc	Power Supply
ORG	Internal Organization
DC	Don't Connect

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■ Figure 1: Block Diagram



■ Electrical Characteristics

► Absolute Maximum Ratings*

▶*NOTICE:

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to this device. These are stress ratings only. Functional operation of this device at these or any other conditions above those indicated in the operational sections of this specification is not implied or intended. Exposure to the absolute maximum rating conditions for extended periods may affect device reliability.

■ Table 2.Pin Capacitance (1)

►Applicable over recommended operating range from TA = 25°C, f = 1.0 MHz, VCC = +1.8V (unless otherwise noted)

Symbol	Test Conditions	Max	Unit	Conditions
COUT	Output Capacitance (DO)	5	pF	VOUT = 0V
CIN	Input Capacitance (CS, SK, DI)	5	pF	VIN = 0V

■ Table 3. DC Characteristics

► Applicable over recommended operating range from: TA = -40°C to +85°C, VCC = +1.8V to +5.5V, (unless otherwise noted)

Symbol	Parameter	Test Cor	ndition	Min	Тур	Max	Units
V _{CC1}	Supply Voltage	-		1.8	-	5.5	V
V_{CC2}	Supply Voltage	-		2.7	-	5.5	V
Vcc3	Supply Voltage	-		4.5	-	5.5	V
Icc	Supply Current	Vcc = 5.0V	Read at 1.0 MHz	-	0.2	2.0	mA
ICC	Зарру Сапен	VCC = 3.0V	Write at 1.0 MHz	-	0.9	3.0	mA
I _{SB1}	Standby Current	Vcc = 1.8V		-	-	1.0	μA
I _{SB2}	Standby Current	Vcc = 2.7V		-	-	1.0	μA
I _{SB3}	Standby Current	Vcc = 5.0V		-	-	1.0	μA
I _{IL(1)}	Input Leakage	V _{IN} = 0V	-	0.1	1.0	μA	
I _{IL(2)}	Input Leakage	V _{IN} = 0V	-	2.0	3.0	μA	
loL	Output Leakage	V _{IN} = 0V	-	0.1	1.0	μA	
V _{IL1(3)}	Input Low Voltage	2.7V ≤ Vc	c < 5.5\/	-0.3	-	0.8	
V _{IH1(3)}	Input High Voltage	2.7 V = VC	. <u> </u>	2.0	-	Vcc + 0.3	V
$V_{\text{IL2(3)}}$	Input Low Voltage	1.8V ≤ Vcc	· < 2.7\/	-0.3	-	Vcc + 0.3	
$V_{\text{IH2(3)}}$	Input High Voltage	1.00 = 000	Vcc x 0.7	-	Vcc + 0.3	V	
V _{OL1}	Output Low Voltage	2.7V ≤ Vcc ≤ 5.5V	IOL = 2.1mA	-	-	0.4	V
V _{OH1}	Output High Voltage	2.7 V = VCC = 3.3 V	IOH = -0.4mA	2.4	-		V
V _{OL2}	Output Low Voltage	1.8V ≤ Vcc ≤ 2.7V	IOL = 0.15mA	-	-	0.2	V
V_{OH2}	Output High Voltage	1.00 = 000 = 2.70	$IOH = -100\mu A$	Vcc-0.2	-	-	V

Notes: 1. DI \sim CS \sim SK input pin

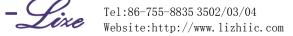
- 2. ORG input pin
- 3. VIL min and VIH max are reference only and are not tested.

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■ Table 4. AC Characteristics

ightharpoonup Applicable over recommended operating range from TA = -40°C to + 85°C, VCC = +1.8V to + 5.5V,

CL = 1 TTL Gate and 100pF (unless otherwise noted)

Symbol	Parameter	Test Co	ondition	Min	Тур	Max	Units
fsк	SK Clock Frequency	4.5V ≤ Vo	cc ≤ ≤5.5V	0	-	2	MHz
		2.7V ≤ Vo	cc ≤ ≤5.5V	0		1	
		1.8V ≤ V	cc ≤ 5.5V	0		0.25	
tsкн	SK High Time	4.5V ≤ Vo	250	-	-	ns	
			cc ≤ ≤5.5V	250			
		1.8V ≤ V	cc ≤ 5.5V	1000			
tskl	SK Low Time	4.5V ≤ Vo	cc ≤ ≤5.5V	250	-	-	ns
			cc ≤ ≤5.5V	250			
		1.8V ≤ V	cc ≤ 5.5V	1000			
tcs	Minimum CS Low Time	4.5V ≤ Vo	cc ≤ ≤5.5V	250	-	-	ns
		2.7V ≤ Vo	cc ≤ ≤5.5V	250			
		1.8V ≤ V	cc ≤ 5.5V	1000			
tcss	CS Setup Time	Relative to SK	4.5V ≤ Vcc ≤ ≤5.5V	50	-	-	ns
			2.7V ≤ Vcc ≤ ≤5.5V	50			
			1.8V ≤ Vcc ≤ 5.5V	200			
tois	DI Setup Time	Relative to SK	4.5V ≤ Vcc ≤ ≤5.5V	100	-	-	ns
			2.7V ≤ Vcc ≤ ≤5.5V	100			
			1.8V ≤ Vcc ≤ 5.5V	400			
t csH	CS Hold Time	Relative to SK		0	-	-	ns
t dih	DI Hold Time	Relative to SK	4.5V ≤ Vcc ≤ ≤5.5V	100	-	-	ns
			2.7V ≤ Vcc ≤ ≤5.5V	100			
			1.8V ≤ Vcc ≤ 5.5V	400			
t _{PD1}	Output Delay to "1"	AC Test	4.5V ≤ Vcc ≤ ≤5.5V	-	-	250	ns
			2.7V ≤ Vcc ≤ ≤5.5V			250	
			1.8V ≤ Vcc ≤ 5.5V			1000	
t _{PD0}	Output Delay to "0"	AC Test	4.5V ≤ Vcc ≤ ≤5.5V	-	-	250	ns
			2.7V ≤ Vcc ≤ ≤5.5V			250	
			1.8V ≤ Vcc ≤ 5.5V			1000	
tsv	CS to Status Valid	AC Test	4.5V ≤ Vcc ≤ ≤5.5V	-	-	250	ns
			2.7V ≤ Vcc ≤ ≤5.5V			250	
			1.8V ≤ Vcc ≤ 5.5V			1000	
tor	CS to DO in High	AC Test	4.5V ≤ Vcc ≤ ≤5.5V	-	-	100	ns
	Impedance	CS = VIL	2.7V ≤ Vcc ≤ ≤5.5V			100	
			1.8V ≤ Vcc ≤ 5.5V			400	
twp (1)	Write Cycle Time	-	-	-	1.5	5	ms
Endurance ⁽¹⁾	5.0V, 25°C		-	1M	-	-	Write Cycle

Notes: 1. This parameter is characterized and is not 100% tested.

■ Functional Description

The L93C46 is accessed via a simple and versatile three-wire serial communication interface. Device operation is controlled by seven instructions issued by the host processor. A valid instruction starts with a rising edge of CS and consists of a start bit (logic"1") followed by the appropriate op code and the desired memory address location.

■ Table5. Instruction Set for the L93C46

Instruction	SB	OP Code	Add	ress	Da	ata	Comments
IIISHUCHOII	SD	OF Code	x8	x16	x8	x16	Comments
READ	1	10	A6 - A0	A5 - A0			Reads data stored in memory, at specified address
EWEN	1	00	11XXXXX	11XXXX			Write enable must precede all programming modes
ERASE	1	11	A6 - A0	A5 - A0			Erase memory location An - A0
WRITE	1	01	A6 - A0	A5 - A0	D7 - D0	D15 - D0	Writes memory location An - A0
ERAL	1	00	10XXXXX	10XXXX			Erases all memory locations. Valid only at VCC = 4.5V to 5.5V
WRAL	1	00	01XXXXX	01XXXX	D7 - D0	D15 - D0	Writes all memory locations. Valid only at VCC = 4.5V to 5.5V
EWDS	1	00	00XXXXX	00XXXX			Disables all programming instructions

Notes: The X's in the address field represent don't care values and must be clocked.

READ (READ): The Read (READ) instruction contains the address code for the memory location to be read. After the instruction and address are decoded, data from the selected memory location is available at the serial output pin DO. Output data changes are synchronized with the rising edges of serial clock SK. It should be noted that a dummy bit (logic "0") precedes the 8- or 16-bit data output string.

ERASE/WRITE (EWEN): To assure data integrity, the part automatically goes into the Erase/Write Disable (EWDS) state when power is first applied. An Erase/Write Enable(EWEN) instruction must be executed first before any programming instructions can be carried out. Please note that once in the EWEN state, programming remains enabled until an EWDS instruction is executed or VCC power is removed from the part.

ERASE (ERASE): The Erase (ERASE) instruction programs all bits in the specified memory location to the logical "1" state. The self-timed erase cycle starts once the ERASE instruction and address are decoded. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (TCS). A logic "1" at pin DO indicates that the selected memory location has been erased, and the part is ready for another instruction.

WRITE (WRITE): The Write (WRITE) instruction contains the 8 or 16 bits of data to be written into the specified memory location. The self-timed programming cycle, tWP, starts after the last bit of data is received at serial data input pin DI. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (TCS). A logic "0" at DO indicates that programming is still in progress. A logic "1" indicates that the memory location at the specified address has been written with the data pattern contained in the instruction and the part is ready for further instructions. A Ready/Busy status cannot be obtained if the CS is brought high after the end of the selftimed programming cycle, TWP.

ERASE ALL (ERAL): The Erase All (ERAL) instruction programs every bit in the memory array to the logic "1" state and is primarily used for testing purposes. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (TCS). The ERAL instruction is valid only at VCC = $5.0V \pm 10\%$.

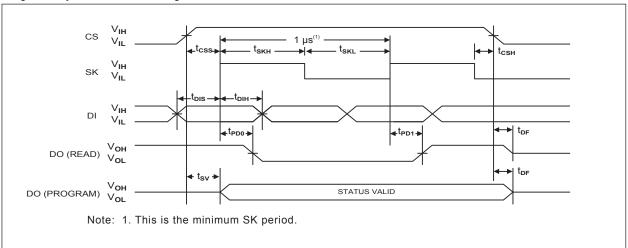
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WRITE ALL (WRAL): The Write All (WRAL) instruction programs all memory locations with the data patterns specified in the instruction. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (TCS). The WRAL instruction is valid only at VCC = $5.0V \pm 10\%$.

ERASE/WRITE DISABLE (EWDS): To protect against accidental data disturb, the Erase/Write Disable (EWDS) instruction disables all programming modes and should be executed after all programming operations. The operation of the Read instruction is independent of both the EWEN and EWDS instructions and can be executed at any time.

■ Timing Diagrams

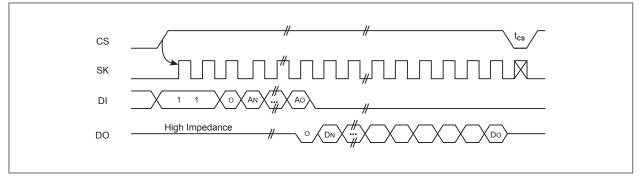
▶ Figure 2: Synchronous Data Timing



■ Table 6. Organization Key for Timing Diagrams

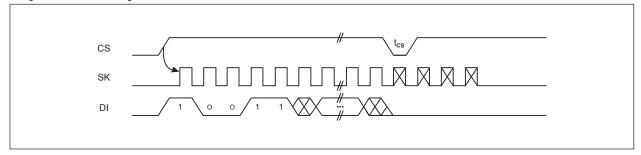
I/O	L93C46(1K)				
170	X 16	X 8			
AN	A5	A6			
DN	D15	D7			

▶ Figure 3: READ Timing

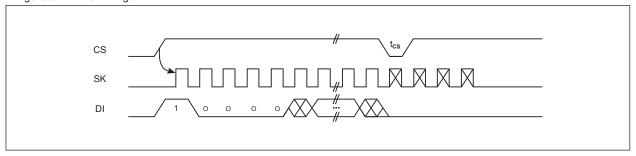


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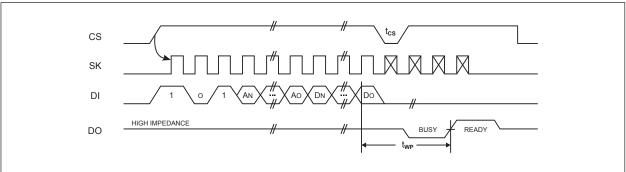




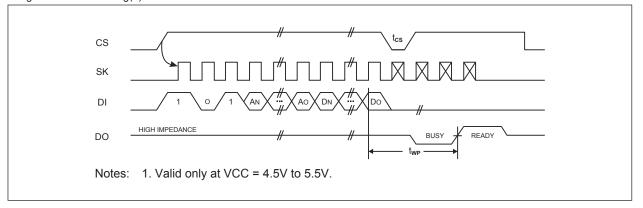
▶ Figure 5: EWDS Timing



▶ Figure 6: WRITE Timing

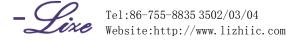


► Figure 7: WRAL Timing(1)

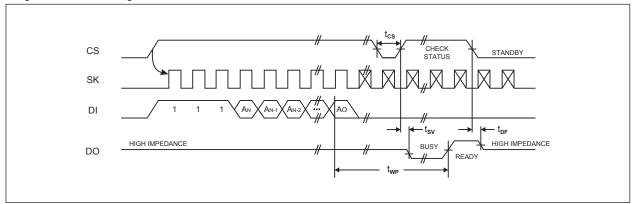


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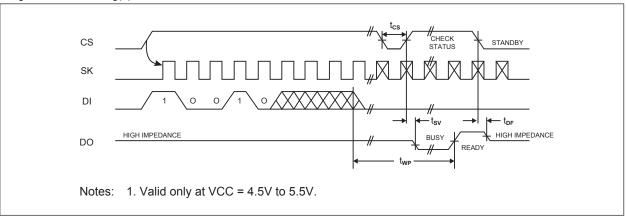
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▶ Figure 8: ERASE Timing



► Figure 9: ERAL Timing(1)



■ Ordering Information

Part Number	L	93	ХХХ	х -	x x x x	x	
	1	2	3	4	5 6 7 8	9	
1.Prefix		4.Design	Option	6. Ten	nperature Range	8.Plating Technology	
2.Series Name		o=□ (Blank) 5.Package Type		C = Com Temp(0 °C-70 °C)		Blank = Standard SnPb plating	
93: Three-wire (SPI) Interfac	e			I = In	nd Temp(-40 °C-85 °C)	G = ECOPACK(RoHS compliant	
` '		D = DIP		E = Exp Temp(-40 °C-125 °C)		9.Operating Voltage	
3.EEPROM Density		S = SOP		7.Pack Type		S=2.7~5.5	
C46=1K bits		T = TSSOP W = Wafer/die		T = T	ube	A=1.8~5.5	
				R = Tape & Reel			

■ Product Datasheet Change Notice

Datasheet Revision History					
Version Content Date					
1.1	Datasheet	2007-9-13			

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L93C46 Series (SPI Bus) Serial EEPROM

Data Sheet, Revision 1.1

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